## NSN 5961-01-450-5955

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**Inclosure Material:** Glass **Overall Length:** Between 0.230 inches and 0.300 inches **Terminal Length:** Between 1.000 inches and 1.500 inches **Overall Diameter:** Between 0.085 inches and 0.130 inches **Function For Which Designed:** Voltage regulator **End Application:** Uhf/receiver e/i fscm 95105 **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 2.4 regulator voltage **Current Rating Per Characteristic:** 2.50 amperes forward current, average peak **Power Rating Per Characteristic:** 400.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Special Features:** Metallurgical bond; junction pattern arrangement: pn **Precious Material And Location:** Terminal surfaces gold **Precious Material:** Gold **Test Data Document:** 81349-mil-prf-19500k specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 uninsulated wire lead **Specification Data:** 

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N/a

Shelf Life:

**Unit Of Measure:** 

81349-mil-s-19500/435 government specification

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Mil-std (military Standard):

Mil-prf-19500k spec.